NSN 5961-01-475-1012

Fiig: A110a0

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-475-1012 **Inclosure Material:** Glass **Overall Length:** Between 0.200 inches and 0.225 inches **Mounting Method:** Terminal **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 19.0 breakdown voltage, dc **Special Features:** Square end cap diodes; 500 watt mx. Peak pulse power; e-melf package Shelf Life: N/a **Unit Of Measure:** Demilitarization: No